

isc Silicon NPN Power Transistor

DESCRIPTION

- DC Current Gain -
- : h_{FE} =30@ I_C= 2A
- · Collector-Emitter Sustaining Voltage-
 - : V_{CEO(SUS)}= 80V(Min)
- Complement to Type BD810
- · Minimum Lot-to-Lot variations for robust device performance and reliable operation



APPLICATIONS

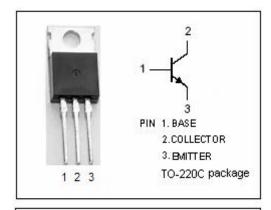
· Designed for use in high power audio amplifiers utilizing complementary or quasi complementary circuits.

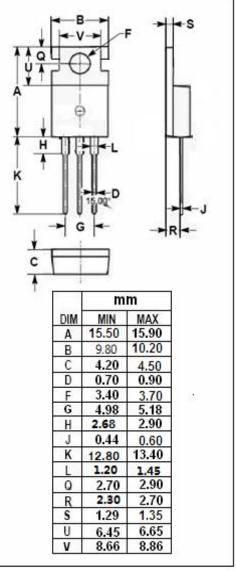
ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

| SYMBOL | PARAMETER | VALUE | UNIT |
|------------------|--|---------|--------------|
| V _{CBO} | Collector-Base Voltage | 80 | V |
| V _{CEO} | Collector-Emitter Voltage | 80 | V |
| V _{EBO} | Emitter-Base Voltage | 5 | V |
| Ic | Collector Current-Continuous | 10 | Α |
| I _B | Base Current | 6 | Α |
| Pc | Collector Power Dissipation @ T _C =25°C | 90 | W |
| Тл | Junction Temperature | 150 | $^{\circ}$ C |
| T _{stg} | Storage Temperature Range | -55~150 | $^{\circ}$ C |

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | MAX | UNIT |
|---------------------|--------------------------------------|------|------|
| R _{th j-c} | Thermal Resistance, Junction to Case | 1.39 | °C/W |







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BD809

ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN | MAX | UNIT |
|-----------------------|--------------------------------------|--|-----|-----|------|
| V _{CEO(SUS)} | Collector-Emitter Sustaining Voltage | I _C = 30mA ;I _B = 0 | 80 | | V |
| V _{CE(sat)} | Collector-Emitter Saturation Voltage | I _C = 3A; I _B = 0.3A | | 1.1 | V |
| V _{BE(on)} | Base-Emitter On Voltage | I _C = 4A; V _{CE} = 2V | | 1.6 | V |
| Ісво | Collector Cutoff Current | V _{CB} = 80V;I _E = 0 | | 1.0 | mA |
| I _{EBO} | Emitter Cutoff Current | V _{EB} = 5V; I _C = 0 | | 2.0 | mA |
| h _{FE-1} | DC Current Gain | I _C = 2A; V _{CE} = 2V | 30 | | |
| h _{FE-2} | DC Current Gain | I _C = 4A; V _{CE} = 2V | 15 | | |
| f⊤ | Current-Gain—Bandwidth Product | I _C = 1.0A; V _{CE} = 10V; f _{test} = 1.0MHz | 1.5 | | MHz |

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